



UNITRODE

DV2003S1

Fast Charge Development System

Control of On-Board P-FET
Switch-Mode Regulator

Features

- bq2003 fast-charge control evaluation and development
- Charge current sourced from an on-board switch-mode regulator (up to 3.0 A)
- Fast charge of 2 to 16 NiCd or NiMH cells
- Fast-charge termination by delta temperature/delta time ($\Delta T/\Delta t$), negative delta voltage ($-\Delta V$), maximum temperature, maximum time, and maximum voltage
- $-\Delta V$ enable, hold-off, top-off, maximum time, and number of cells are jumper-configurable
- Charging status displayed on charge and temperature LEDs
- Discharge-before-charge control with push-button switch
- Inhibit fast charge by external logic-level input

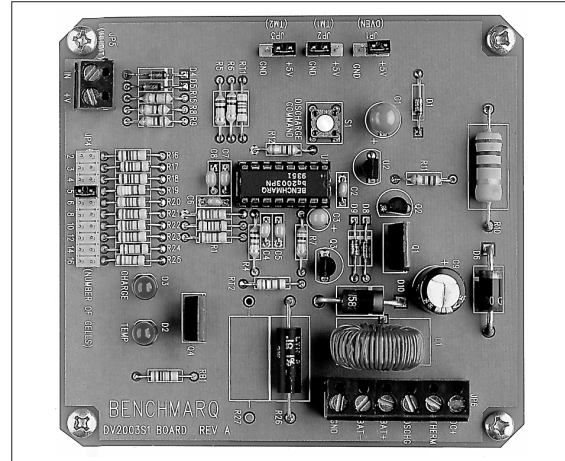
General Description

The DV2003S1 Development System provides a development environment for the bq2003 Fast-Charge IC. The DV2003S1 incorporates a bq2003 and a buck-type switch-mode regulator to provide fast charge control for 2 to 16 NiCd or NiMH cells.

Review the bq2003 data sheet and the application note, "Using the bq2003 to Control Fast Charge," before using the DV2003S1 board.

The fast charge is terminated by any of the following: $\Delta T/\Delta t$, $-\Delta V$, maximum temperature, maximum time, maximum voltage, or an external inhibit command. Jumper settings select the $-\Delta V$ enabled state, and the hold-off, top-off, and maximum time limits.

The user provides a power supply and batteries. The user configures the DV2003S1 for the number of cells, $-\Delta V$ charge termination and maximum charge time (with or without top-off), and commands the discharge-before-charge option with the push-button switch S1.



Connection Descriptions

J6

DC+	DC input from charger supply
THERM	Thermistor connection
DSCHG	Low side of discharge load
BAT+	Positive battery terminal and high side of discharge load
BAT-	Negative battery terminal and thermistor connection
GND	Ground from charger supply

J2

+V	Voltage source for inhibit input
IN	Inhibit input to prevent bq2003 activity
JP1 DVEN	Negative voltage termination enable
JP2 TM1	TM1 setting
JP3 TM2	TM2 setting
JP4 NOC	Select number of cells

DV2003S1

Fixed Configuration

The DV2003S1 board has the following fixed characteristics:

V_{CC} (4.75–5.25V) is regulated on-board from the supply at connector JP6 DC+.

LEDs indicate charge status and temperature fault status.

Pin CCMD is grounded, providing charge initiation on the later application of the battery or DC+, which provides V_{CC} to the bq2003.

Pin DCMD is pulled to ground through R12. A toggle of switch S1 momentarily pulls DCMD high and initiates a discharge-before-charge. The bq2003 output activates FET Q4, allowing current to flow through an external current-limiting load between BAT+ and DSCHG on connector JP6.

Trickle current is limited by a 150Ω/2W resistor R10 between DC+ and BAT+ (maximum potential across R10 = 17.3V). Note that too large a voltage between DC+ and BAT+ may exceed the wattage rating of resistor R10.

As shipped from Benchmarq, the DV2003S1 buck-type switch-mode regulator is configured to a charging current of 2.35A. This current level is controlled by the value of sense resistor R26 by the relationship:

$$I_{CHG} = \frac{0.235V}{R26}$$

The value of R26 at shipment is 0.100Ω. This resistor can be changed depending on the application.

The suggested maximum I_{CHG} for the DV2003S1 board is 3A. A location for a second sense resistor (R27) is provided on the DV2003S1 Board. R27 is electrically in parallel with R26, which assists in user modification of I_{CHG}, if needed.

Charge current can be halted at any time via external stimulus. Connector JP5 provides a +5V DC source (+V) and an inhibit input (IN) node for this function. To inhibit charge current, the JP5 inhibit input (IN) is driven by +5V DC. To reinitiate charge, remove the voltage source from the inhibit input.

The maximum cell voltage (MCV) setting is 1.8V.

Zener diode D1 is used to limit Q1 V_{GS} per a given DC+ voltage. Benchmarq ships a 1N751A (5.1V Zener) at location D9. This voltage value was selected as an appropriate value for most development work. The user can modify this Zener diode for the application. Refer to Table 1 for suggested D9 values for DC+ voltages.

Table 1. Lookup Table for D9 Selection

+VDC Input (Volts)	Motorola Part No.	Nominal Zener Voltage
Below 15	Shorted	0
15–18	1N749	4.3
18–21	1N755	7.5
21–24	1N758	10
24–27	1N964A	13
27–30	1N966A	16
30–32	1N967A	18
32–35	1N968A	20

With the provided NTC thermistor connected between THERM and BAT–, values are: L_TF = 10°C, H_TF = 45°C, and T_{CO} = 50°C. The ΔT/Δt settings at 30°C (T_{ΔT}) are: minimum = 0.82°C/minute, typical = 1.10°C/minute.

The thermistor is identified by the serial number suffix as follows:

Identifier	Thermistor
K1	Keystone RL0703-5744-103-S1
(blank)	Philips 2322-640-63103
F1	Fenwal Type 16, 197-103LA6-A01

Jumper-Selectable Configuration

The DV2003L1 must be configured as described below.

DVEN (JP1): Enables/disables -ΔV termination (see bq2003 data sheet).

Jumper Setting	Pin State
[1 2] 3	Enabled (high)
1 [2 3]	Disabled (low)

TM1 and TM2 (JP2 and JP3): Select fast charge safety time/hold-off/top-off (see bq2003 data sheet).

Jumper Setting	Pin State
[1 2] 3	High
1 [2 3]	Low
1 2 3	Float

Number of Cells (JP4): A resistor-divider network is provided to select 2 to 16 cells (the resulting resistor value equals $N - 1$ cells). RB1 is a 200K Ω resistor, and RB2 (R16–R22) is jumper-selected.

Closed Jumper	Number of Cells
R22	14
R21	12
R20	10
R19	8
R18	6
R17	5
R16	4

Temperature Disable: Connecting a 10K Ω resistor between THERM and BAT– disables temperature control.

Setup Procedure

1. Configure DVEN, TM1, TM2, and number-of-cells (NOC) jumpers.
2. Connect the provided thermistor or a 10K Ω resistor between THERM and BAT–.

Note: RT1 and RT2 match the thermistor provided and must be changed if a different thermistor type is used (see Appendix A in the application note, “Using the bq2003 to Control Fast Charge”).

3. If using the discharge-before-charge option, connect a current-limiting discharge load between BAT+ and DSCHG.
4. If using the INHIBIT function, connect a switch across JP5 (IN to +V) or connect IN to the controlling signal source (3–5V).
5. Attach the battery pack to BAT+ and BAT–. For temperature control, the thermistor must contact the cwlls.
6. Attach DC current source to DC+ (+) and GND (–) connections in JP6.

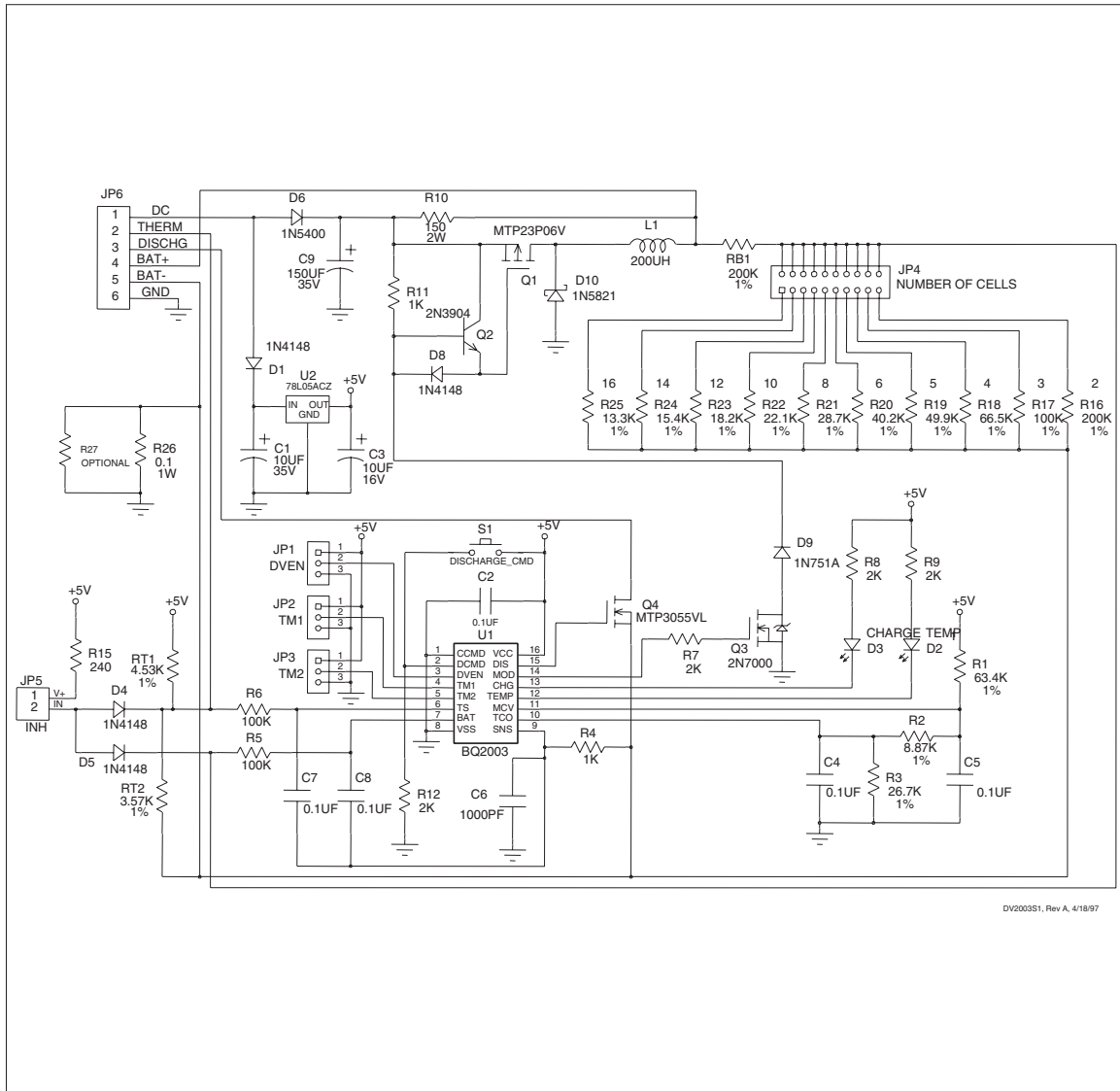
Recommended DC Operating Conditions

Symbol	Description	Minimum	Typical	Maximum	Unit	Notes
I_{DC+}	Maximum input current	-	-	2.4	A	
V_{DC}	Maximum input voltage	$2.0 + V_{BAT+}$ or 15	-	$18 + V_{BAT+}$ or 35	V	Note 1
V_{BAT+}	BAT+ input voltage	-	-	30	V	
V_{THERM}	THERM input signal	0	-	5	V	
I_{DSCHG}	Discharge load current	-	-	2	A	

Note: 1. The V_{DC+} limits consider the 5.1V Zener diode at D9. The voltage at D9 is application-specific and limits the V_{GS} of Q1 to a safe enhancement value during Q1 conduction. See Table 1 for recommended D9 selections per V_{DC+} .

DV2003S1

DV2003L1 Board Schematic



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